

SANYO Semiconductors DATA SHEET



Bi-CMOS IC LV23200T — For Home Stereo System 1-chip Tuner IC Incorporating PLL

Overview

The LV23200T is a one-chip tuner IC incorporating PLL for home stereo system.

Functions

- AM tuner Changeover of the constant in RFAMP, MIX, OSC, IF AMP, DET, AGC, SD, OSC BUFF, IF BUFF, and AGC modes.
- FM tuner 1stIFAMP, IF limiter AMP, DET (COIL type), S-METER, SD, AFC, IF BUFF.
- MPX PLL STEREO DECODER, forced MONO, AUDIO MUTE, function to prevent interference from a neighboring station, PILOT canceling function.
- PLL frequency synthesizer.

Features

- Tuner IC and PLL IC integrated into one chip.
- MPX-VCO incorporated and without need of adjustment.
- FM/AM output level independent setting possible.
- MOS transistor for active LPF incorporated.

Specitications

Maximum Ratings at $Ta = 25 \ ^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	V _{CC}	7.0	V
	V _{DD} max	V _{DD}	6.0	V
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-40 to +125	°C

- Any and all SANYO Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO Semiconductor representative nearest you before using any SANYO Semiconductor products described or contained herein in such applications.
- SANYO Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor products described or contained herein.

Operating Condition at $Ta = 25 \ ^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	VCC		5.0	V
	V _{DD}		3.0	V
Operating supply voltage range	V _{CC} op		4.5 to 6.0	V
	V _{DD} op1	X'tal oscillation = 4.5MHz	2.7 to 3.3	V

* Handle pin 34 with care because its electrostatic voltage at C = 200 pF and $R = 0\Omega$ is 110 V.

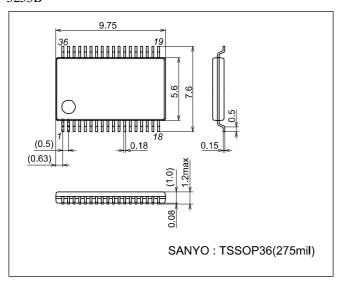
Operating Characteristics at Ta = 25°C, V_{CC} = 5.0V, V_{DD} = 3.0V

Parameter	Symbol	Conditions		Ratings		Unit
	Symbol	Contaillons	min	typ	max	Unit
[Current dissipation]						
FM tuner block	ICCEM	No input in FM mode	25	35	45	mA
AM tuner block	ICCAM	No input in AM mode	14	24	34	mA
PLL block	I _{DD} FM	X'tal = 4.5MHz, No input at tuner	2.0	3.0	4.0	mA
[FM-FE characteristics (MPX)] :	FM-IF (5PIN) inpu	t, fc = 10.7MHz, fm = 1kHz, 75kHzdev (L+R = 90	0%, Pilot = 10%)			
Demodulation output	VO	$V_{IN} = 100 dB \mu V$	450	550	650	mVrms
3dB sensitivity 1	LS1	V _{IN} = 70dBµV reference, input at -3dB ∗at input of FIFA (pin 1)		28	33	dBμV
3dB sensitivity 2	LS2	V _{IN} = 100dBµV reference, input at -3dB ∗at input of FMFA (pin 5)		35	40	dBμV
Total harmonic distortion	THD1	V _{IN} = 100dBμV, MONO		0.4	1.5	%
Signal-to-noise ratio	S/N	V _{IN} = 100dBμV	70	76		dB
AM suppression ratio	AMR	V _{IN} = 100dBµV, AM = 30%	36	40		dB
SD sensitivity	SD-1	0%mod, SD sensitivity mode 1	43	50	57	dBμV
Total harmonic distortion	THD2	V _{IN} = 100dBµV, MAIN-MOD		0.5	1.5	%
Separation	SEP	$V_{IN} = 100 dB\mu V$, L output/R output	30	45		dB
ST sensitivity	VL	$V_{IN} = 100 dB\mu V$, (L+R)+Pilot		3.0	5.5	%
Mute attenuation	MUTE	V _{IN} = 100dBμV, L output		60		dB
Carrier leakage	CL	V _{IN} = 100dBµV, (L+R)+Pilot	30	40		dB
[AM characteristics] : fc = 999kH	lz, fm = 1kHz, 30%	śmod				
Demodulation output 1	V _O 1	V _{IN} = 23dBµV, 30%mod, fm = 1kHz	50	80	130	mVrm
Demodulation output 2	V _O 2	V _{IN} = 80dBµV, 30%mod, fm = 1kHz	170	240	310	mVrm
Signal-to-noise ratio 1	S/N1	V _{IN} = 23dBµV	15	20		dB
Signal-to-noise ratio 2	S/N2	V _{IN} = 80dBµV	48	54		dB
Total harmonic distortion	THD	$V_{IN} = 80 dB \mu V$		0.4	1.3	%
SD sensitivity	SD-ON	0%mod (Internally fixed sensitivity)	14	24	34	dBμV
[PLL characteristics]	·					
Internal return resistance	Rf	XIN		8		MΩ
Built-in output resistance	Rd	XOUT		250		kΩ
Hysteresis width	VHIS	CE, CL, DI		0.1V _{DD}		V
Output high level voltage	VOH	PD ; I _O = -1mA	V _{DD} -1.0			V
Output low level voltage	V _{OL} 1	PD ; I _O = 1mA			1.0	V
	V _{OL} 2	BO ; I _O = 1mA			0.25	V
		BO ; I _O = 5mA			1.25	V
	V _{OL} 3	DO ; I _O = 1mA			0.25	V
	V _{OL} 4	AOUT ; I _O = 1mA, AIN = 2.0V			0.5	V
Output high level voltage	I _{IH} 1	CE, CL, DI ; VI = 6.0V		ľ	5.0	μΑ
	I _{IH} 2	XIN ; VI = V _{DD}	0.16		0.9	μA
	I _{IH} 3	AIN ; VI = 6.0V			200	nA
Input high level current	I _{IL} 1	CE, CL, DI ; VI = 0V		ľ	5.0	μΑ
	I _{IL} 2	XIN ; VI = 0V	0.16		0.9	μA
	IIL3	AIN ; VI = 0V			200	nA

Continued from preceding page.						
Parameter	Symbol	Conditions		Ratings		Unit
Falameter	Symbol	Conditions	min	typ	max	Unit
Output off-leak current	IOFF ¹	BO, AOUT ; V _O = 10V			5.0	μA
	IOFF ²	DO ; V _O = 6.0V			5.0	μA
"H" level 3-state off-leak current	IOFFH	PD ; V _O = 6.0V		0.01	200	nA
"L" level 3-state off-leak current	IOFFL	PD ; V _O = 0V		0.01	200	nA

Package Dimensions

unit : mm 3253B



Description of Pin Functions

1 FM tstF-AMP input 1.0V Input impedance if (Rin). 2 REG 2.2V Imput impedance of (Rin). 3 FM tst F-AMP output 3.0V Imput impedance ro (Rout). 4 AM MX output. VCC Imput impedance ro (Rout). 5 FM IF input Vreg Imput impedance ro (Rout). 6 GND OV AMFM IF/MPX block GND 7 AM IF input 2.2V Imput impedance ro (Rout).	No.	Functions	Voltage (V)	Internal Equivalent Circuit	Remarks
3 FM 1st IF-AMP output 3.0V Image: second se	1	FM 1stIF-AMP input	1.6V		
4 AM MIX output V _{CC} 4 MIX coll used between pins 4 and 8 (V _{CC} voltage). 5 FM IF input Vreg Input impedance ri (Rin). Rin 6 GND OV 7 AM IF input 2.2V	2	REG	2.2V		block.
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	3	FM 1st IF-AMP output	3.0V	Rout	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	4	AM MIX output	Vcc		
7 AM IF input 2.2V Input impedance ri (Rin). 7 AM IF input Input impedance ri (Rin). Rin Rin	5	FM IF input	Vreg		
7 $Rin = 2k\Omega$	6	GND	0V		AM/FM IF/MPX block GND
	7	AM IF input	2.2V		
8 V _{CC} 5.0V AM/FM IF/MPX block V _{CC}	8	V _{CC}	5.0V		AM/FM IF/MPX block V _{CC}

No.	Functions	Voltage (V)	Internal Equivalent Circuit	Remarks
9	FM DET	VCC		Recommended detection coil. 600BCAS–10790Z
10	Phase comparator filter	V _{CC} -1.0V		R = 10kΩ
11	Pilot filter	V _{CC} -1.0V		R = 10kΩ
12 13	L output R output	2.5V	Rout (13)	Output impedance ro (Rout). Rout = 7.7kΩ
15	CE	-	(15) S O	Chip enable pin At changeover from "L" to "H": Address latching. At changeover from "H" to "L": Data latching.
16	DI	_	(16) S O	Serial data input pin Sets data in synchronization with rise of data clock.
17	CL	_	(17)S	Data clock input pin.
18	DO	_		Data output pin Outputs various data in synchronization with fall of data clock in the OUT mode.

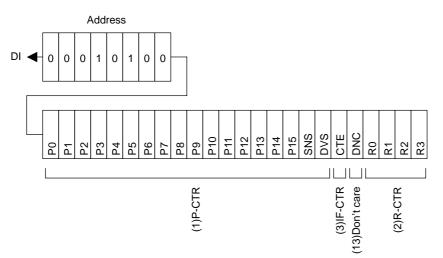
Ne	Eunotiona	Voltage (V)	Internal Equivalent Oravit	Demostra
No. 19 20	Functions X IN X OUT	Voltage (V) – –	19 (19) (20) Internal Equivalent Circuit	Remarks Clock for internal reference Connect a 4.5 MHz crystal oscillator.
21	V _{DD}	3.0V		AM/FM IF/MPX block V _{DD}
22	Pilot canceling output	Vreg	Rout 22	Output impedance ro (Rout). Rout = 30kΩ
23	AM detection output	0.8V (FM) Vreg (AM)	Rout 23	Output impedance ro (Rout). Rout = 10kΩ
24	MPX input	Vreg	24 RNF C24	MPX inverse input pin. RNF = 20kΩ
25	PLL input	Vreg	25 Rin	Input impedance ri (Rin). Rin = 20kΩ
26	FM detection output	Vreg+0.7V	Rout Rout	Output impedance ro (Rout). Rout = $3.3k\Omega$ Adjusts separation using the capacitance value of a section between this pin and GND.

No.	Functions	Voltage (V)	Internal Equivalent Circuit	Remarks
27	SD monitor	V _{DD}	V _{DD} 27	Active "L" Open collector.
28	FMS meter and AM AGC outputs	0.2V (FM) 0.8V (AM)	28 R	Internal load resistance R = 13.9kΩ Determines the SD response speed during SEEK by a capacitor externally connected to pin 28.
29	PD	-	29	PLL charge pump output pin.
30 31	AIN AOUT	-	30 30 31 7//	Nch MOS transistor for PLL active low pass filter.
32	AM OSC	Vcc	32	OSC coil used between pins 32 and 8 (V _{CC} voltage).
33	AFC	Vreg	33	Enables adjustment of the FM SD band width by external resistor between pins 33 and 2 (Vreg voltage).

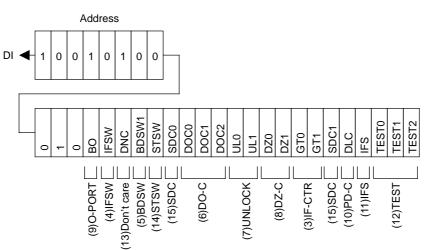
No.	Functions	Voltage (V)	Internal Equivalent Circuit	Remarks
34	AM RF input	Vreg	34	Use pin 34 with the same potential as for pin 32 (AFC voltage).
35	FM OSC input	Vcc	35 VCC	Use pin 35 through pull-up to pin 8 (V _{CC} voltage) by resistance load.
36	BO	_	36 	Pin dedicated for output.

Composition of DI control data (serial data input)

(1) IN1 mode



(2) IN2 mode



Description of DI control Data

No.	Control block data					Descript	ion			Related data		
(1)	Programmable	Data	 Data to set the dividing number of programmable divider 									
	divider data	Binary	Binary value with P15 assumed to be MSB. LSB varies according to DVS and SNS.									
			(* : Don't care)									
	P0 to P15		DVS SNS LSB set dividing number (N) Actual dividing									
	DVS, SNS		1	*	P0	272 to 65535		Twice the set value				
			0 1 P0 272 to 65535			Set value						
			0 0 P4 4 to 4095 Set value									
		* P0 to	P3 invali	id when	LSB : P4	1						
		• To se	lect the s	signal inp	out (FMI	N, AMIN) to the prog	ramma	ble divider and to change the	input			
		freque	ency ran	ge.								
								(* : Don't care)				
			DVS	SNS		Input	Op	eration frequency range				
			1 * FMIN 10 to 160MHz									
			0 1 AMIN 2 to 40MHz									
			0	0		AMIN		0.5 to 10MHz				

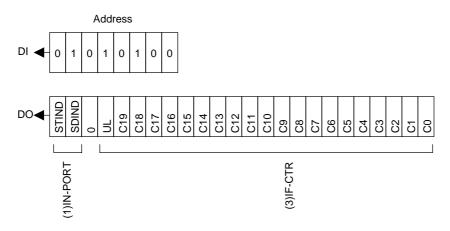
No.	Control block data						Descri	ption		Related data
(2)	Reference	Refer	ence fre	quency (fref) sele	ection dat	a			
	divider data		R3	R2	R1	R0		Reference frequency		
	R0 to R3		0	0	0	0		25kHz		
	KU 10 K3		0	0	0	1		25kHz		
			0	0	1	0		25kHz		
			0	0	1	1		25kHz		
			0	1	0	0		12.5kHz		
			0	1	0	1		6.25kHz		
			0	1	1	0		3.125kHz		
			0	1	1	1		3.125kHz		
			1	0	0	0		5kHz		
			1	0	0	1		5kHz		
			1	0	1	0		5kHz		
			1	0	1	1		1kHz		
			1	1	0	0		3kHz		
			1	1	0	1		15kHz		
			1	1	1	0		PLL INHIBIT+X'tal OSC		
			1	1	1	1		PLL INHIBIT		
			rogramn					vith FMIN, AMIN, HCTR and LC	IR inputs being in	
(3)	IF counter			inting sta			<u>J</u> - I	<u> </u>		IFS
(-)	control data			unting st						
				unting st						
	CTE			-		of univers	al counte	r		
	GT0, GT1		GT1	GT0	~	ounting ti		Wait time		
			0	0	0	4ms	ine	3 to 4ms		
			0	1		8ms		3 to 4ms		
			1	0		16ms		3 to 4ms		
			1	1		32ms		3 to 4ms		
	• • •				L					
(4)	MUTE	Data to determine the output of output port IFSW, controlling the MUTE function. "Data" = 0 : at receiving 1 : MUTE Data to determine the output of output port BDSW, controlling selection of BAND.								
	control data									
	IFSW									
(5)	FM/AM BAND									
(-)	selection		a" = 0 : A			1.16.20	, u	J		
	control data		1:F							
	BDSW									

No.	Control block data					Description	n		Related data				
(6)	DO pin	• Data	to control	DO pin ou	utput				UL0, UL1				
	control data		DOC2	DOC1	DOC0		DO pin condition		CTE				
				-		Onon	DO pin condition						
	DOC0		0	0	0	Open	all is detected						
	DOC1		0 0	0	1 0	Low when unlo	he item with asterisk below)						
	DOC2		0	1	1	Open	ne item with astensk below)						
			1	0	0	Open							
			1	0	1	Low when SD0	N						
			1	1	0	Low when ster							
			1	1	1	Open							
		• The o	pen cond	lition is sel	ected at po	ower ON/reset.							
		* IF cou	inter cour	nting end o	check								
			DO pin		$\mathcal{N}_{\mathbb{I}}$		»"						
				1 Co	ounting sta	rt ② Co	ounting end ③ CE : HI						
							I), DO pin opens automatically.						
				-			W and check on counting end c	an be made.					
			•			ntered/output (CE	. ,						
				-	-	-	data input (IN1 and IN2 modes,	-					
						-	 In the DO pin condition during Operial data is output in synchromial 						
		(OUT mode, CE-Hi period), the content of internal DO serial data is output in synchronization with CL pin signal, regardless of DO pin control data (DOC).											
(7)	Unlock detection	 Phase error (\(\phi\)E) detection width selection data to judge if PLL is locked. 											
(7)	data						to mean that PLL is locked		DOC0 DOC1				
	dulu	1 1100		loooding u		i mainio juagoa	(* : don't care)		DOC2				
	UL0, UL1		UL1	UL0	φE Dete	ection width	Detection output						
			0	0		Stop	Open						
			0	1		0	Direct output of ϕE						
			1	*	±6	δ.67μs	φE extended by 1 to 2 ms						
		* DO pi	n is LOW	. Serial da	ta output :	UL = 0.							
(8)	Phase					ase comparator							
	comparator		D74	D70	Deed								
	control data		DZ1	DZ0		zone mode							
			0	0		DZA							
	DZ0, DZ1		0	1		DZB DZC							
			1 1	0 1		DZC							
		Dead			DZB <dzc·< td=""><td></td><td>I</td><td></td><td></td></dzc·<>		I						
(9)	Output port data					ports BO1 and B	02						
. ,			a" = 0 : O		1.00								
	BO		1 : Lo	wc									
(10)	Charge pump	Data	to enforce	e control o	f charge pu	Imp output							
	control data		DLC	Charge	pump outp	ut							
			0		lormal								
	DLC		1		ed to LOW								
		* In cas				O oscillation stop	when the VCO control voltage (Vtune) is 0V. it					
						-	ump output to LOW and V tune t						
			lear circu		,	5 · · ····.50 P	,	00 (
(11)	IFS	Normally, set Data = 1. Setting Data = 0 causes the input sensitivity worsening mode and the											
					-		· · · · ·						
(12)	LSI test data	sensitivity decreases by about 10 to 30mVrms. • LSI test data											
		TE	ST0 –										
	TEST0 to 2	TEST1 All to be set to "0"											
		TE	ST2										
				power ON	l/reset				ļ				
(13)	DNC	 Set data 	ata = 0.										

No.	Control block data	Description	Related data
(14)	Forced monaural control data	 Data to determine the output of output port STSW, controlling the forced stereo functions. "Data" = 0 : MONO STEREO 	
	STSW		
(15)	SD sensitivity	Data to determine the output of output ports SDC, controlling the SD sensitivity	
	control data	"Data" = SDC0 : 0, SDC1 : 0 \rightarrow SD sensitivity 1 = 50dB μ V (Typ)	
		SDC0 : 0, SDC1 : 1 \rightarrow SD sensitivity 2 = 52dB μ V (Typ)	
	SDC	SDC0 : 1, SDC1 : 0 \rightarrow SD sensitivity 3 = 57dB μ V (Typ)	
		SDC0 : 1, SDC1 : 1 \rightarrow SD sensitivity 4 = 62dB μ V (Typ)	
		* Above data values indicate the difference of SD sensitivity levels and are reference values.	

DO control data (serial data output) composition

(1) OUT mode



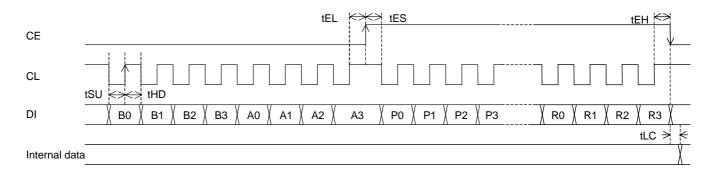
Description of DO output data

No.	Control block data	Description	Related data
(1)	Stereo and SD	Data latching stereo and SD indicator conditions.	
	indicators	Latching made in the data output (OUT) mode.	
	control data	SDIND Stereo indicator condition 0 : ST ON, 1 : ST OFF	
		STIND—SD indicator condition 0 : SD ON, 1 : SD OFF	
	STIND, SDIND		
(2)	PLL unlock data	Data latching the content of unlock detection circuit	UL0
		UL←0 : At unlock	UL1
	UL	1 : At lock or in the detection stop mode	
(3)	IF counter,	Data latching the content of IF counter (20-bit binary counter)	CTE
	binary counter	C19←MSB of binary counter	GT0
		C0 ←LSB of binary counter	GT1
	C19 to C0		

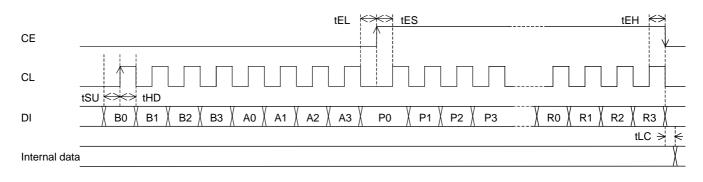
LV23200T

Serial data input (IN1/IN2) tSU, tHD, tEL, tES, tEH≥0.75µs tLC<0.75µs

CL : Normally Hi

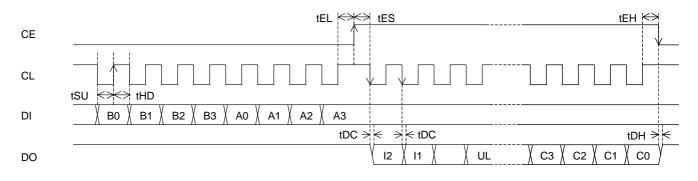


CL : Normally Low

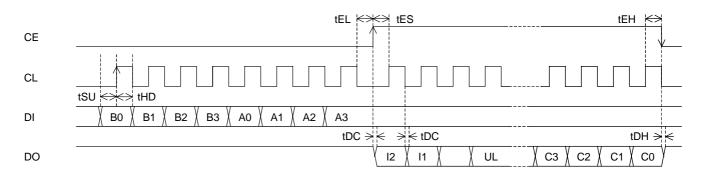


Serial data output (OUT) tSU, tHD, tEL, tES, tEH 20.75 µs tDC, tDH < 0.35 µs

CL : Normally Hi

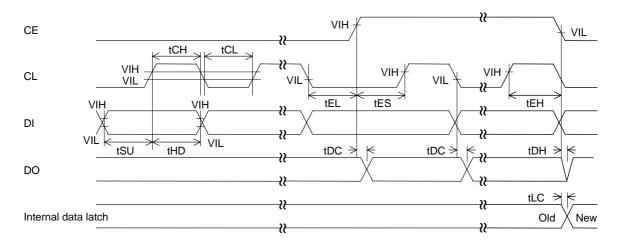


CL : Normally Hi

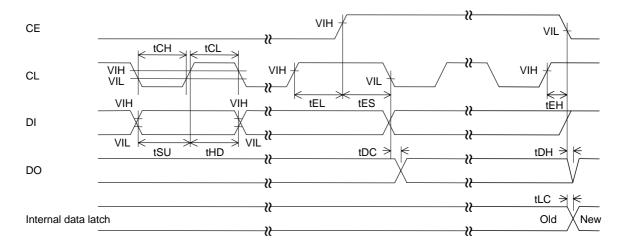


(Note) DO pin is an Nch open drain pin, so that the data varying time (tDC and tDH) differs depending on the pull-up resistance and substrate capacity.

Serial data timing



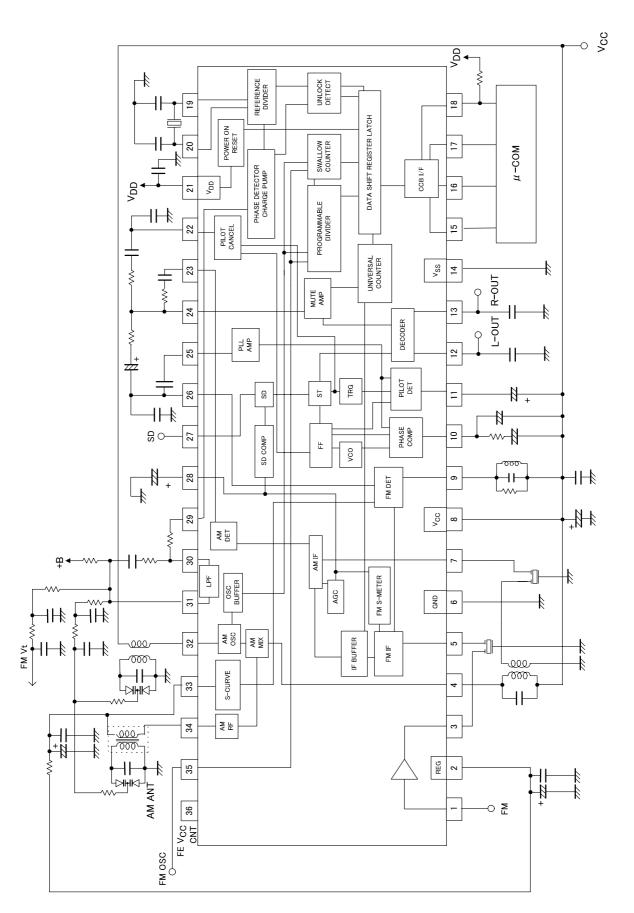
<< When CL stops at the "L" level >>



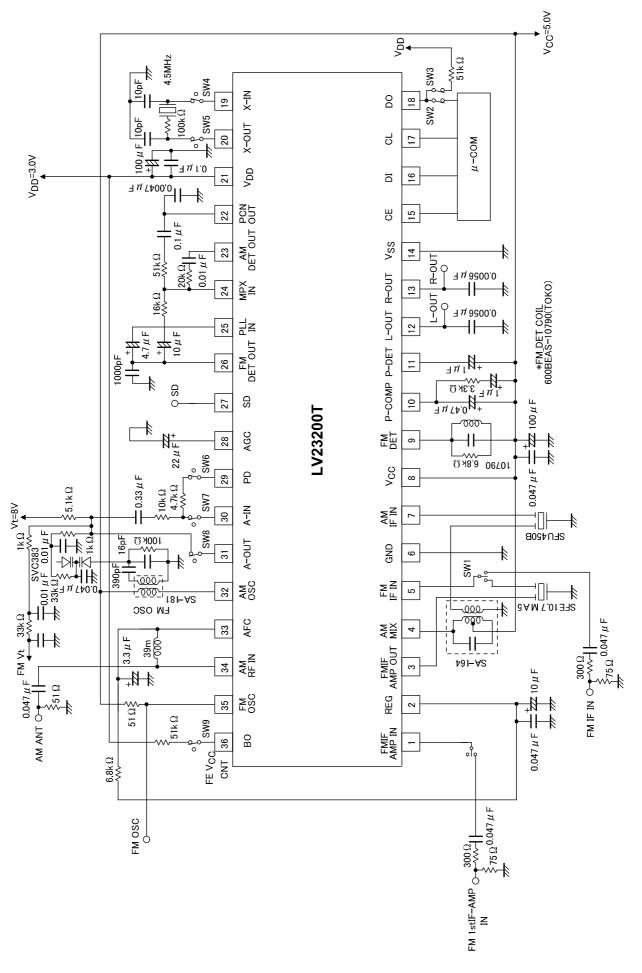
<< When CL stops at the "H" level >>

Parameter	Symbol	Pin	Conditions	Min	Тур	Max	Unit
Data setup time	tSU	DI, CL		0.75			μs
Data hold time	tHD	DI, CL		0.75			μs
Clock "L" level time	tCL	CL		0.75			μs
Clock "H" level time	tCH	CL		0.75			μs
CE wait time	tEL	CE, CL		0.75			μs
CE setup time	tES	CE, CL		0.75			μs
CE hold time	tEH	CE, CL		0.75			μs
Data latch change time	tLC					0.75	μs
Data output time	tDC	DO, CL	Differs depending on the pull-up resistance			0.35	μs
	tDH	DO, CE	and substrate capacity				

Block Diagram



Test Circuit



- Specifications of any and all SANYO Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Semiconductor Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 2005. Specifications and information herein are subject to change without notice.